# Surface Mount General Purpose Silicon Rectifiers

Reverse Voltage - 2000 V

Forward Current - 1 A

#### **FEATURES**

- For surface mounted applications
- · Low profile package
- Glass Passivated Chip Juntion
- · Easy to pick and place
- Lead free in comply with EU RoHS 2011/65/EU directives

#### **MECHANICAL DATA**

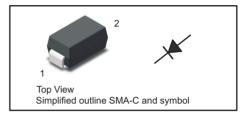
· Case: SMA-C

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.055g / 0.002oz

#### **PINNING**

| PIN | DESCRIPTION |  |
|-----|-------------|--|
| 1   | Cathode     |  |
| 2   | Anode       |  |



#### Maximum Ratings and Electrical characteristics

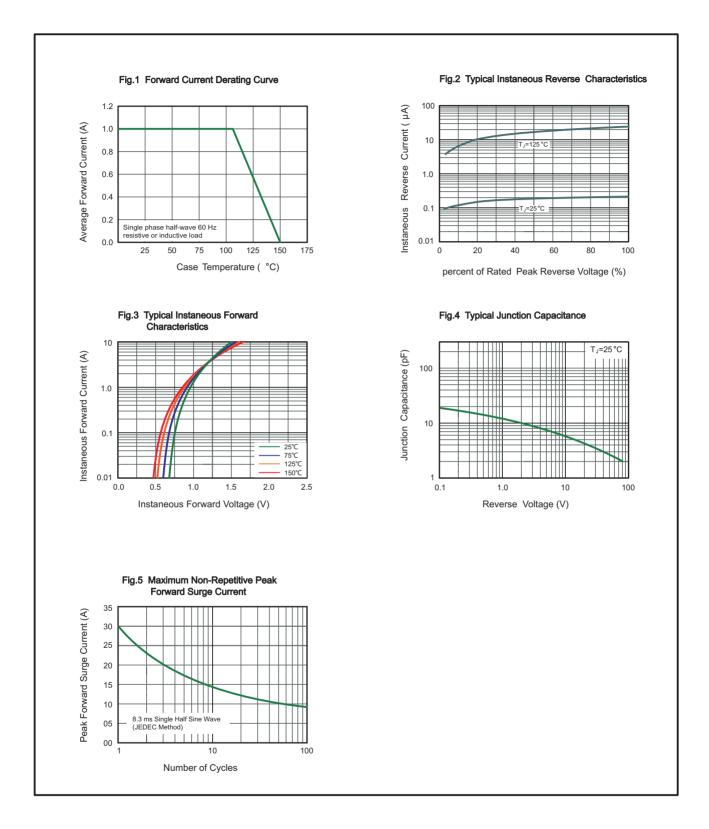
Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

| Parameter  | Symbols   | S1YAC           | Units            |
|--|---|-----------------|------------------|
| Maximum Repetitive Peak Reverse Voltage  | $V_{RRM}$   | 2000            | V                |
| Maximum RMS voltage  | V <sub>RMS</sub>  | 1400            | V                |
| Maximum DC Blocking Voltage  | V <sub>DC</sub>   | 2000            | V                |
| Maximum Average Forward Rectified Current @ Fig.1  | I <sub>F(AV)</sub>  | 1               | А                |
| Peak Forward Surge Current,8.3ms Single Half Sine-wave<br>Superimposed on Rated Load (JEDEC method)              | I <sub>FSM</sub>  | 30              | А                |
| Peak Forward Surge Current,1ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)                   | I <sub>FSM</sub>  | 60              | А                |
| I²t Rating for fusing(3ms≤t≤8.3ms)   | l <sup>2</sup> t  | 3.7             | A <sup>2</sup> S |
| Maximum Instantaneous Forward Voltage at 1 A   | V <sub>F</sub>  | 1.1             | ٧                |
| Maximum DC Reverse Current $T_j = 25 ^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_j = 125 ^{\circ}\text{C}$ | I <sub>R</sub>  | 5<br>100        | μΑ               |
| Typical Junction Capacitance (1)   | C <sub>j</sub>  | 8               | pF               |
| Typical Thermal Resistance (2)   | $egin{array}{c} {\sf R}_{	heta {\sf JA}} \ {\sf R}_{	heta {\sf JC}} \ {\sf R}_{	heta {\sf JL}} \end{array}$ | 100<br>20<br>25 | °C/W             |
| Operating and Storage Temperature Range  | $T_{j}, T_{stg}$  | -55 ~ +150      | °C               |

<sup>(1)</sup> Measured at 1 MHz and applied reverse voltage of 4 V D.C

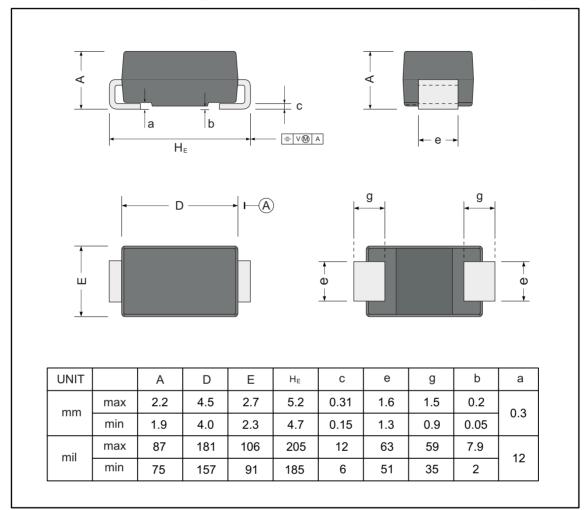
<sup>(2)</sup> P.C.B. mounted with 0.2"X 0.2" (5 X 5 mm) copper pad areas.



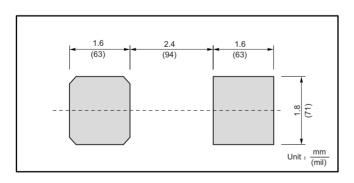
# PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMA-C



## The recommended mounting pad size



### Marking

| Type number | Marking code |
|-------------|--------------|
| S1YAC       | S1Y          |

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